



Shanghai Lunsure Electronic
Technology Co.,Ltd
Tel:0086-21-37185008
Fax:0086-21-57152769

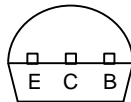
BF420
BF422

Features

- Capable of 0.83Watts of Power Dissipation.
- Collector-current 0.1A
- Collector-base Voltage: BF420 300V
BF422 250V
- Operating and storage junction temperature range: -55°C to +150°C

NPN Silicon
Plastic-Encapsulate
Transistor

Pin Configuration
Bottom View



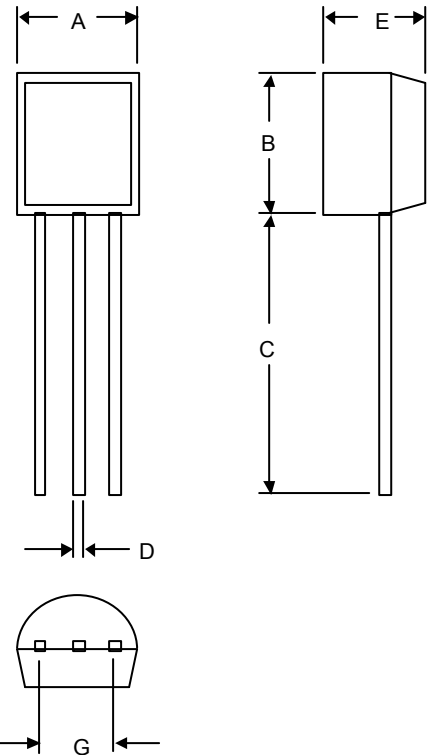
Electrical Characteristics @ 25°C Unless Otherwise Specified

Symbol	Parameter	Min	Max	Units
OFF CHARACTERISTICS				
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage ($I_C=1.0mA$, $I_B=0$)	BF420 300	---	Vdc
		BF422 250	---	
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage ($I_C=100\mu A$, $I_E=0$)	BF420 300	---	Vdc
		BF422 250	---	
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage ($I_E=100\mu A$, $I_C=0$)	5.0	---	Vdc
I_{CBO}	Collector Cutoff Current ($V_{CB}=200Vdc$, $I_E=0$)	---	0.01	μA
I_{EBO}	Emitter Cutoff Current ($V_{EB}=5.0Vdc$, $I_C=0$)	---	0.05	μA

ON CHARACTERISTICS

h_{FE}	DC Current Gain ($I_C=25mA$, $V_{CE}=20Vdc$)	50	---	---
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage ($I_C=30mA$, $I_E=5.0mA$)	---	0.6	Vdc
fT	Transition Frequency ($V_{CE}=10Vdc$, $I_C=10mA$, $f=100MHz$)	60	---	MHz

TO-92



DIMENSIONS

DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.170	.190	4.33	4.83	
B	.170	.190	4.30	4.83	
C	.550	.590	13.97	14.97	
D	.010	.020	0.36	0.56	
E	.130	.160	3.30	3.96	
G	.010	.104	2.44	2.64	